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DTU Fotonik Department of Photonics Engineering



Hybrid III-V-on-Si Laser with Ultra-low Energy Consumption

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Motivation

• Optical Interconnect: low power consumption and high speed modulation for on-chip interconnection technology • Main goal: Development of a comprehensive laser simulator to investigate different micro-laser structures

Rate Equation

- Model the electrical and optical performance of a laser
- Calculate carrier and photon density in different modes
- Analyze dynamics of the laser
- We used modal model to solve these equations

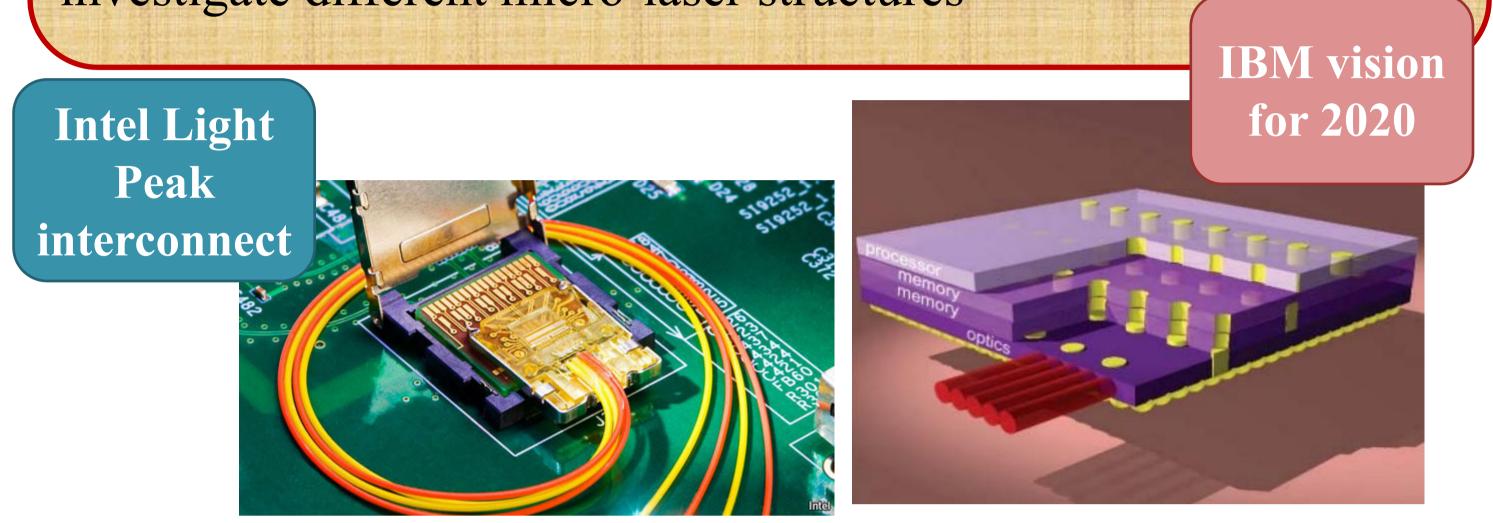
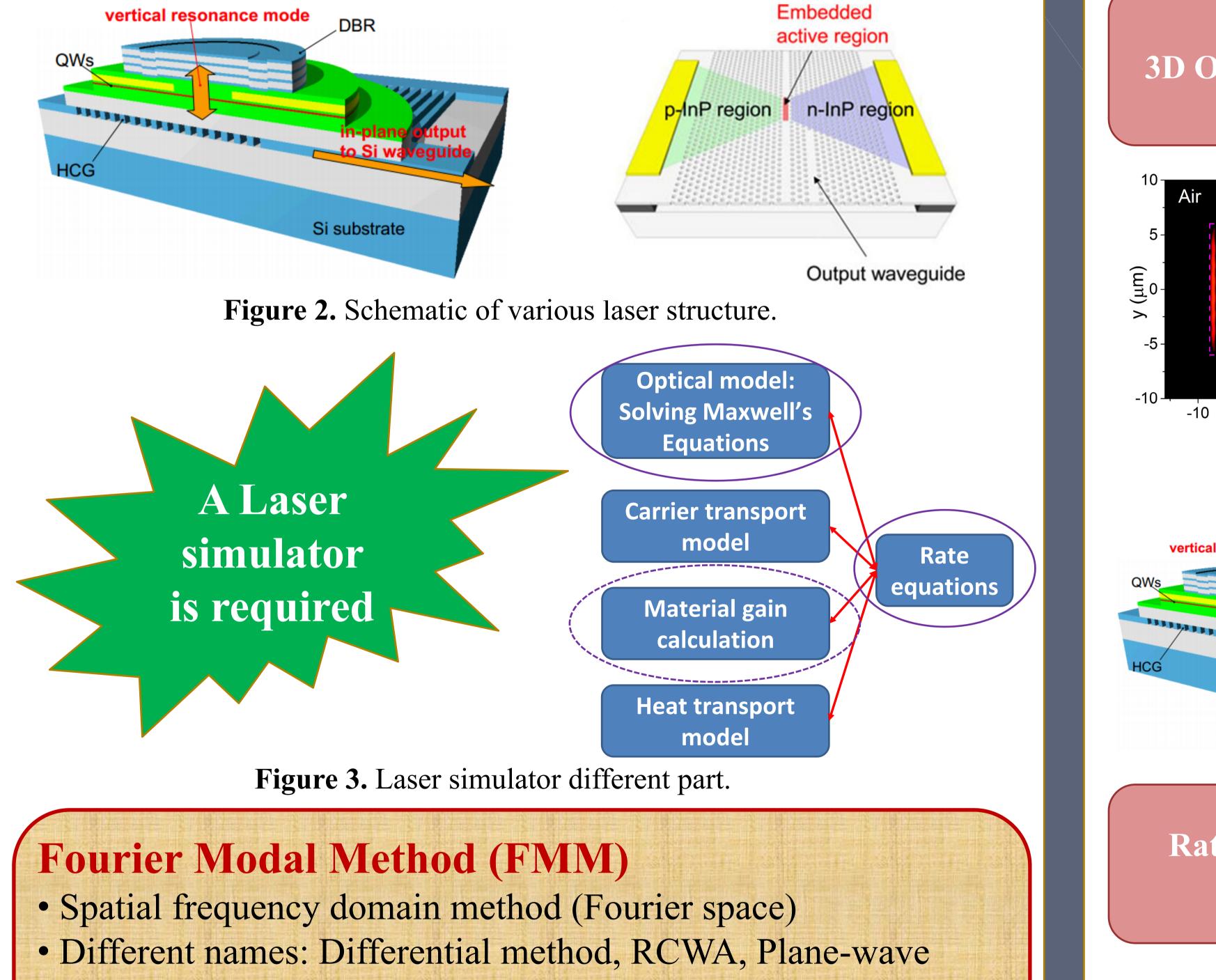
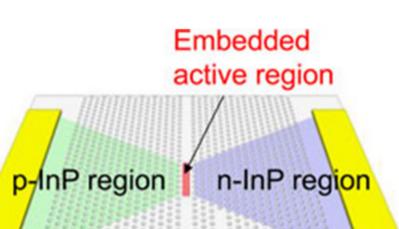


Figure 1. Schematic of the future photonic networks.

Interesting Device Structures

- 1) Different VCSEL structures with DBR and/or PCM mirrors
- Resonance cavity enhanced photodetectors
- 3) Photonic crystal based waveguides and devices



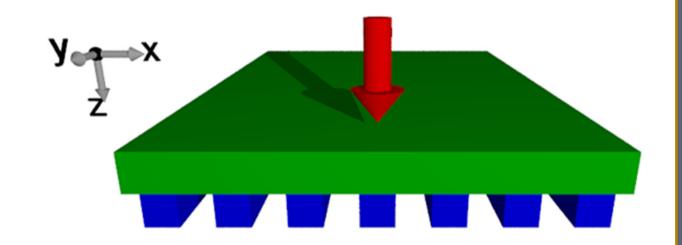


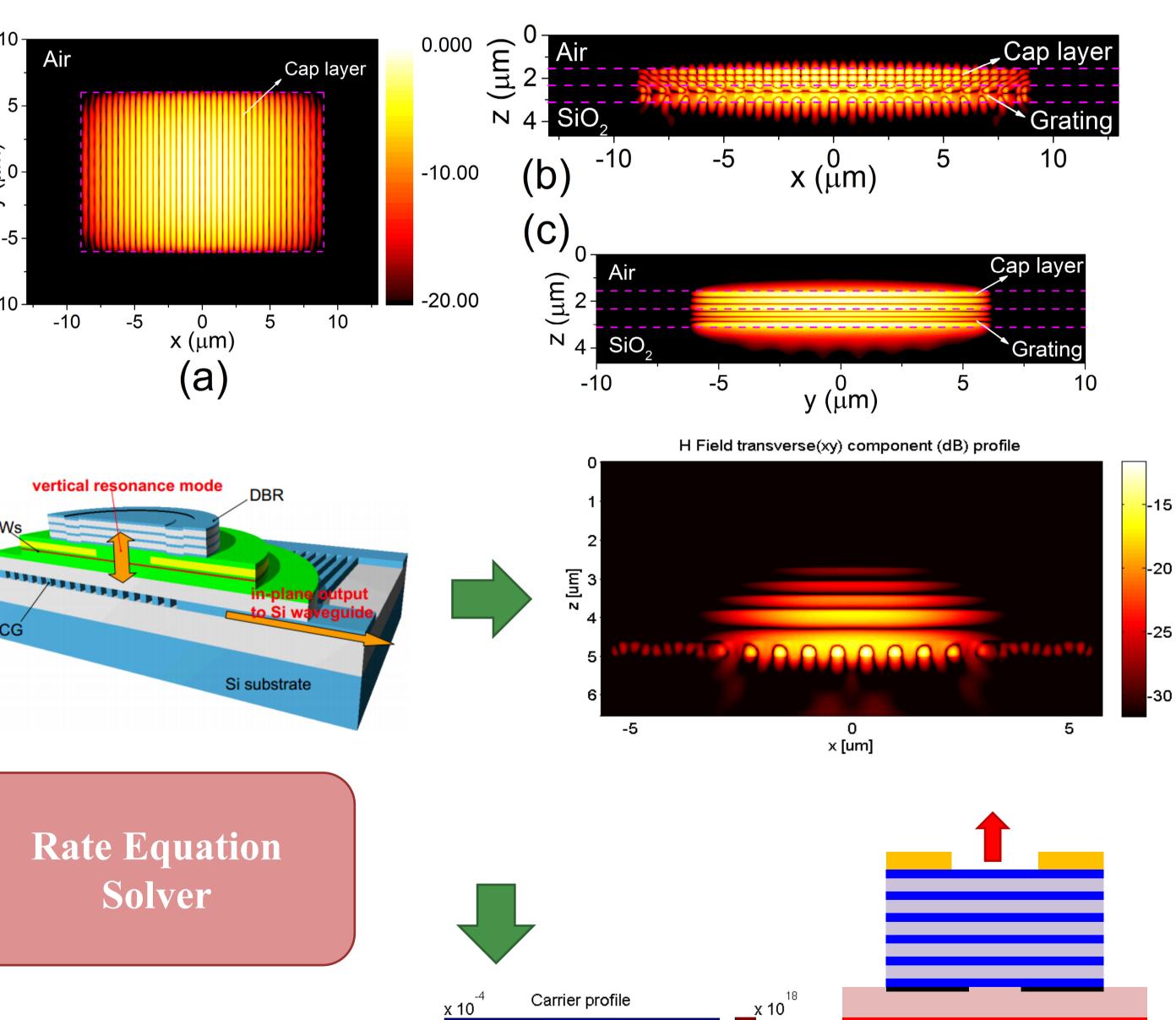
$$\begin{aligned} \frac{\partial N(x_1, x_2, t)}{\partial t} &= \frac{\eta_i I(x_1, x_2, t)}{qV} - \frac{N(x_1, x_2, t)}{\tau_N} + D_N \nabla^2 N(x_1, x_2, t) \\ &- \sum_m G_m(x_1, x_2, t) S_m(t) \\ \frac{\partial S_m(t)}{\partial t} &= -\frac{S_m(t)}{\tau_{sm}} + \frac{\beta_m \Gamma_m}{\tau_N A_m} \iint N(x_1, x_2, t) dA \\ &+ \frac{\Gamma_m}{A_m} S_m(t) \iint G_m(x_1, x_2, t) dA \end{aligned}$$

Simulation Examples

- A compact Hybrid grating resonator
- VCSEL with PCM mirror
- Conventional VCSEL with rectangular current aperture







method, ...

• All electromagnetic quantities are expanded in Fourier series • Layered discretization, Expansion on modes of layers

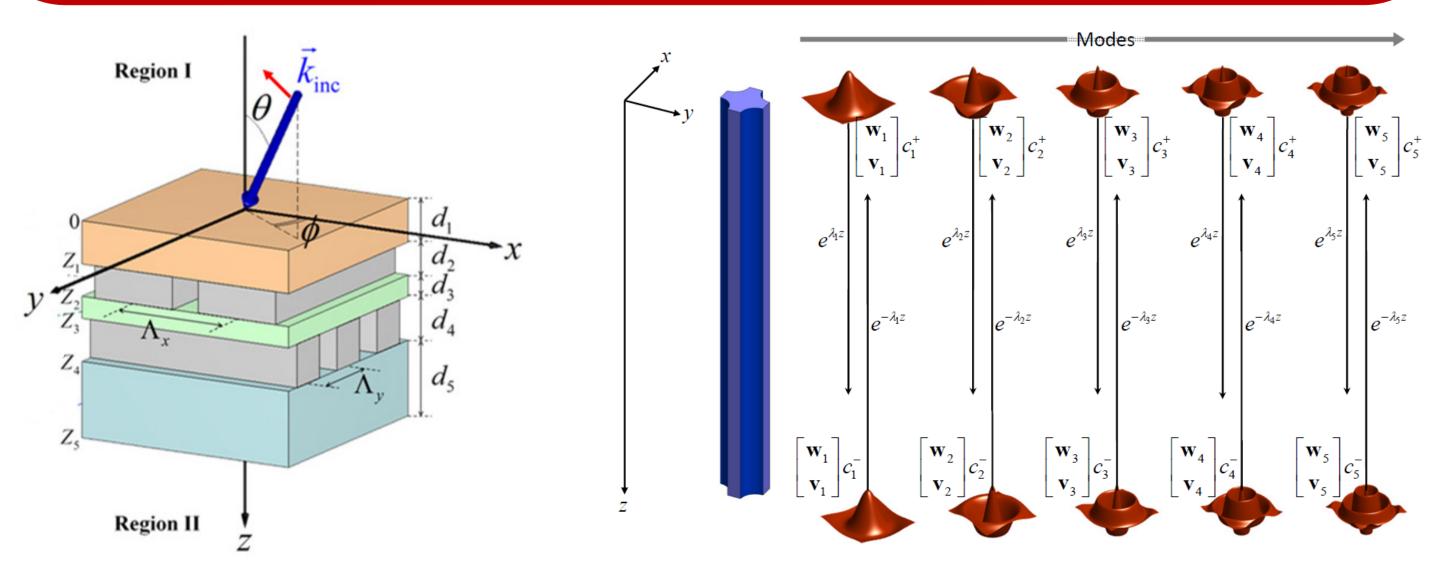


Figure 4. Schematic of a typical device structure and FMM procedure.

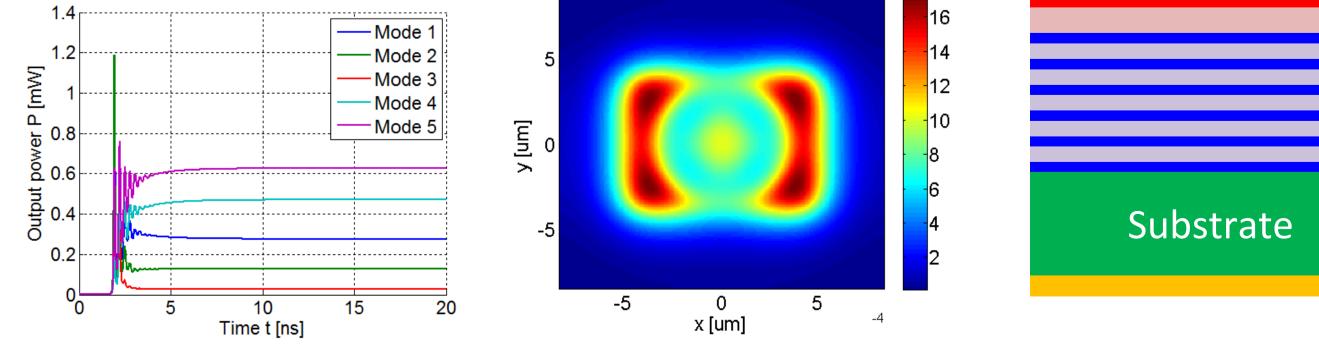


Figure 5. Several simulated structure and their results.

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